

# MBR40H35CT thru MBR40H60CT

Vishay General Semiconductor

# **Dual Common-Cathode Schottky Rectifiers**

High Barrier Technology for Improved High Temperature Performance





PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 20 A					
$V_{RRM}$	35 V to 60 V					
I <sub>FSM</sub>	350 A, 320 V					
$V_F$ at $I_F = 20 A$	0.55 V, 0.60 V					
I <sub>R</sub>	100 μΑ					
T <sub>J</sub> max.	175 °C					

### **FEATURES**

- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- · Low leakage current
- High forward surge capability
- High frequency operation
- Solder dip 275 °C max., 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

### TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application.

### **MECHANICAL DATA**

Case: TO-220AB

Molding compound meets UL 94V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	MBR40H35CT	MBR40H45CT	MBR40H50CT	MBR40H60CT	UNIT		
Maximum repetitive peak reverse voltage	$V_{RRM}$	35	45	50	60	V		
Maximum average forward rectified total device		40						
current (Fig. 1) per diode	I <sub>F(AV)</sub>	20						
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	350		320		Α		
Peak repetitive reverse surge current per diode at t <sub>p</sub> = 2 µs, 1 kHz	I <sub>RRM</sub>	1.0				Α		
Peak non-repetitive reverse surge energy (8/20 µs waveform) per diode	E <sub>RSM</sub>	20			mJ			
Non-repetitive avalanche energy at 25 °C, I <sub>AS</sub> = 3.0 A, L = 5 mH per diode	E <sub>AS</sub>	22.5			mJ			
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000				V/µs		
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 65 to + 175				°C		



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)										
PARAMETER	SYMBOL	TEST CONDITIONS		MBR40H35CT	MBR40H45CT	MBR40H50CT	MBR40H60CT	UNIT		
Maximum instantaneous forward voltage per diode	V <sub>F</sub> <sup>(1)</sup>	$I_F = 20 A$	T <sub>J</sub> = 25 °C	0.64		0.68		V		
		I <sub>F</sub> = 20 A	T <sub>J</sub> = 125 °C	0.55		0.60				
		I <sub>F</sub> = 40 A	T <sub>J</sub> = 25 °C	0.76		0.83				
		I <sub>F</sub> = 40 A	T <sub>J</sub> = 125 °C	0.70		0.	73			
Maximum instantaneous reverse current per diode	I <sub>R</sub> <sup>(2)</sup> ra	rated \/	T <sub>J</sub> = 25 °C	100			μΑ			
		rated V <sub>R</sub>	T <sub>J</sub> = 125°C	15			mA			
Typical junction capacitance	CJ	4.0 V, 1 N	1Hz per diode	1200 920			pF			

#### **Notes**

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1  $\%\,$  duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	MBR40H35CT MBR40H45CT MBR40H50CT MBR40H60CT					
Thermal resistance, junction to case per diode	$R_{ heta JC}$	1.8				°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	ACKAGE PREFERRED P/N UNIT WEIGHT (g) PACKAGE CODE BASE QUANTITY DELIVERY							
TO-220AB	MBR40H45CT-E3/45	1.58	45	50/tube	Tube			

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

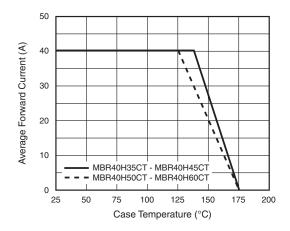


Fig. 1 - Forward Derating Curve Per Diode

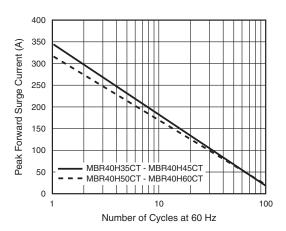


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

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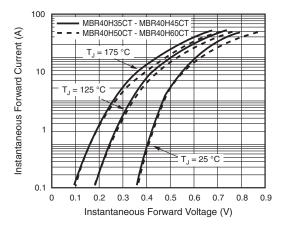


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

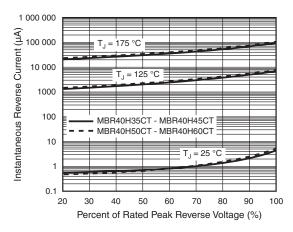


Fig. 4 - Typical Reverse Characteristics Per Diode

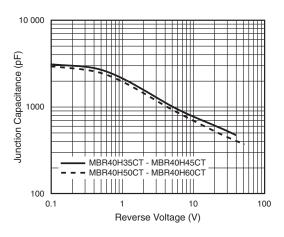


Fig. 5 - Typical Junction Capacitance Per Diode

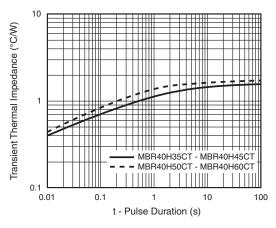
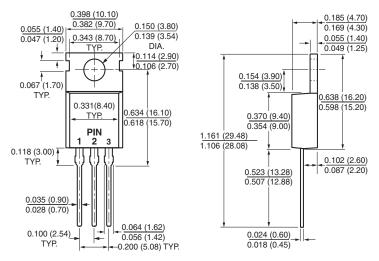


Fig. 6 - Typical Transient Thermal Impedance Per Diode

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

### **TO-220AB**





## **Legal Disclaimer Notice**

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